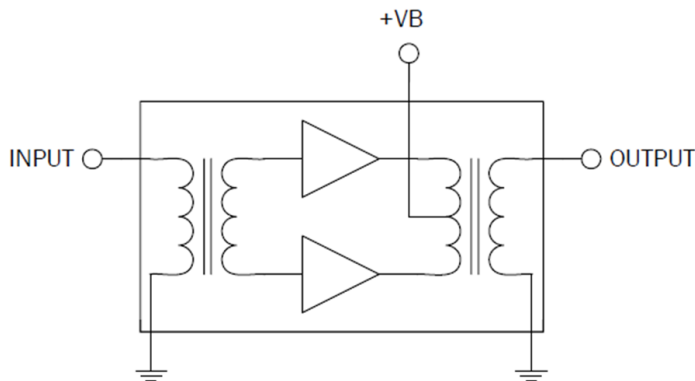


R1005250L

25dB Reverse Hybrid
5MHz to 100MHz (Low Current)

The R1005250L is a hybrid reverse amplifier. The part employs a silicon die. It has extremely low distortion and superior return loss performance. The part also provides optimal reliability with low noise and is well suited for 5MHz to 100MHz CATV amplifiers for reverse channel systems.



Package: SOT-115J

Features

- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Low Noise
- Unconditionally Stable Under All Terminations
- 25.5dB Typical Gain at 100MHz
- 140mA Max. at 24VDC

Applications

- 5MHz to 100MHz CATV Amplifier For Reverse Channel Systems

Ordering Information

R1005250L Box with 50 pieces

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone)	65	dBmV
DC Supply Over-Voltage (5 minutes)	30	V
Storage Temperature	-40 to +100	°C
Operating Mounting Base Temperature	-30 to +100	°C



Caution! ESD sensitive device.



RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2011/65/EU.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

Nominal Operating Parameters

Parameter	Specification			Unit	Condition
	Min	Typ	Max		
General Performance					V+ = 24V; T_{MB} = 30°C; Z_S = Z_L = 75Ω
Power Gain	24.8	25.3	25.8	dB	f = 5MHz
	24.6	25.5		dB	f = 100MHz
Slope ^[1]	-0.2	0.2	0.5	dB	f = 5MHz to 100MHz
Flatness of Frequency Response			±0.3	dB	f = 5MHz to 100MHz (peak to valley)
Input Return Loss	-20			dB	f = 5MHz to 100MHz
Output Return Loss	-20			dB	
Noise Figure		3.4	3.6	dB	f = 100MHz
Total Current Consumption (DC)	125.0	133	140.0	mA	
Distortion Data 5MHz to 100MHz					V+ = 24V; T_{MB} = 30°C; Z_S = Z_L = 75Ω
CTB			-69	dBc	7 ch flat; V ₀ = 50dBmV ^[2]
			-65	dBc	12 ch flat; V ₀ = 50dBmV ^[3]
XMOD			-59	dBc	7 ch flat; V ₀ = 50dBmV ^[2]
			-55	dBc	12 ch flat; V ₀ = 50dBmV ^[3]
CSO			-70	dBc	7 ch flat; V ₀ = 50dBmV ^[2]
			-70	dBc	12 ch flat; V ₀ = 50dBmV ^[3]

1. The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.

2. 7 channels, NTSC frequency raster: T7 - T13 (7.0MHz to 43MHz), +50dBmV flat output level.

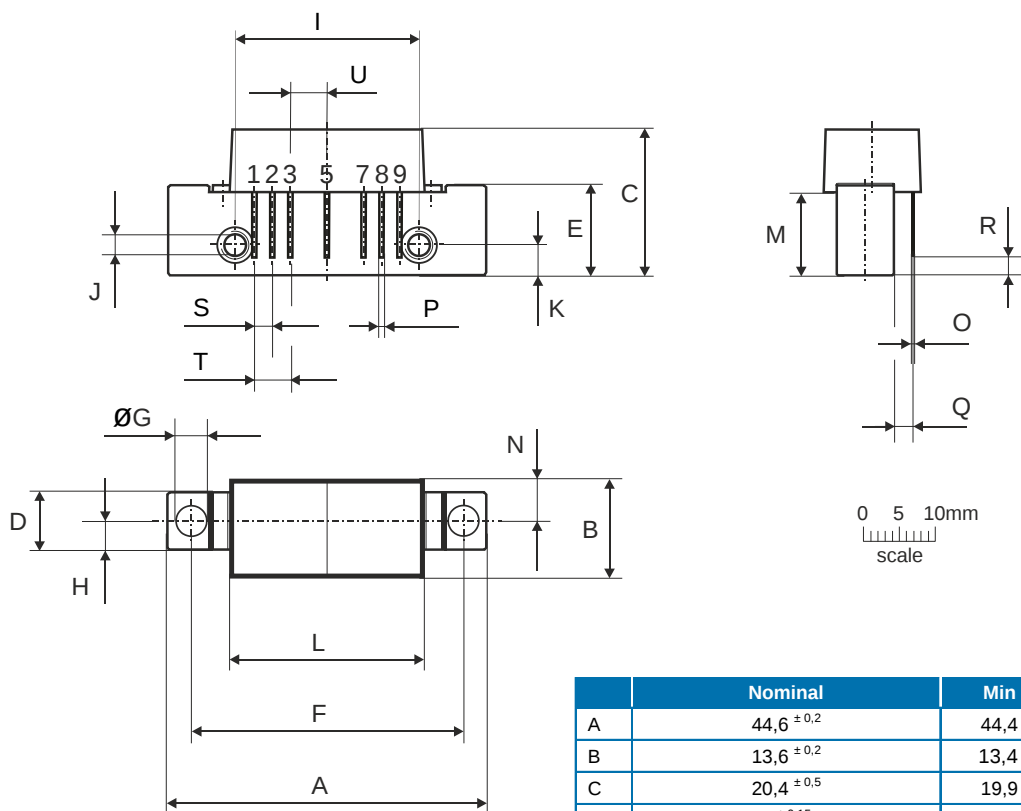
3. 12 channels, NTSC frequency raster: T7 - T13 (7.0MHz to 43MHz), 2 - 6 (55.25MHz to 83.25MHz), +50dBmV flat output level.

Composite Second Order (CSO) - The CSO parameter (both sum and difference products) is defined by the NCTA.

Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.

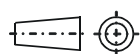
Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.

Package Drawing (Dimensions in millimeters)



Notes:

European
Projection



Pinning:

Pin	Name
1	Input
2-3	GND
4	
5	+VB
6	
7-8	GND
9	Output

	Nominal	Min	Max
A	44,6 ± 0,2	44,4	44,8
B	13,6 ± 0,2	13,4	13,8
C	20,4 ± 0,5	19,9	20,9
D	8 ± 0,15	7,85	8,15
E	12,6 ± 0,15	12,45	12,75
F	38,1 ± 0,2	37,9	38,3
G	4 ^{+0,2 / -0,05}	3,95	4,2
H	4 ± 0,2	3,8	4,2
I	25,4 ± 0,2	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ± 0,2	4,0	4,4
L	27,2 ± 0,2	27,0	27,4
M	11,6 ± 0,5	11,1	12,1
N	5,8 ± 0,4	5,4	6,2
O	0,25 ± 0,02	0,23	0,27
P	0,45 ± 0,03	0,42	0,48
Q	2,54 ± 0,3	2,24	2,84
R	2,54 ± 0,5	2,04	3,04
S	2,54 ± 0,25	2,29	2,79
T	5,08 ± 0,25	4,83	5,33
U	5,08 ± 0,25	4,83	5,33